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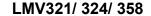
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GENERAL PURPOSE, LOW VOLTAGE, RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS

Description

The LMV321/LMV358/LMV324 are low voltage (2.7V to 5.5V) single, dual and quad operational amplifiers. The LMV321/LMV358/LMV324 are designed to effectively reduce cost and space at low voltage levels.

These devices have the capability of rail-to-rail output swing and input common-mode voltage range includes ground. They can also achieve an efficient speed-to-power ratio, utilizing 1 MHz bandwidth and 1V/µs slew rate at a low supply current. Reducing noise pickup and increasing signal integrity can be achieved by placing the device close to the signal source.

The LMV321 is available in 5-Pin SOT353/SOT25 packages that reduce space on PC boards and portable electronic devices. The LMV324 is available in the SO-14 and TSSOP-14 package.

The LMV358 is available in the MSOP-8 and SO-8 packages.

Features

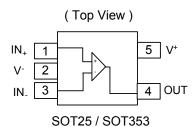
(For V^+ = 5V and V^- = 0V typical unless otherwise noted)

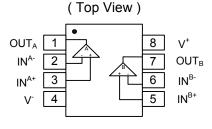
- Guaranteed 2.7V and 5V Performance
- Crossover Distortion Eliminated
- Operating Temperature Range (-40°C to +125°C)
- Gain-bandwidth Product 1 MHz
- Low Supply Current

LMV321 110μA Typ
 LMV358 190μA Typ
 LMV324 340μA Typ

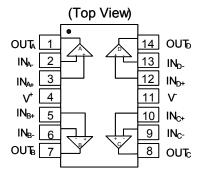
- Rail-to-Rail Output Swing @ 10kΩ
 - V⁺ -10 mV
 - V⁻ +10 mV
- Input Common Mode Voltage Range (-0.2 to V⁺-0.8V)
- · Manufactured in Standard CMOS Process
- SOT353, SOT25, MSOP-8, SO-8, SO-14 & TSSOP-14:
 Available in "Green" Molding Compound (No Br, Sb)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments





SO-8 / MSOP-8



SOP-14L / TSSOP-14L

Applications

- Active Filters
- General Purpose Low Voltage Applications
- General Purpose Portable Devices

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter		Rating	Unit
		LMV321	4.0	
ESD HBM	Human Body Model ESD Protection	LMV358	4.0	KV
		LMV324	4.5	
		LMV321	350	
ESD MM	Machine Model ESD Protection	LMV358	350	V
		LMV324	250	
	Differential Input Voltage		±Supply Voltage	V
V* -V-	Supply Voltage		5.5	V
	Output Short Circuit to V ⁺		(Note 5)	
	Output Short Circuit to V		(Note 6)	
T _{ST}	Storage Temperature		-65 to +150	°C
TJ	Maximum Junction Temperature		+150	°C

Notes:

- 5. Shorting output to V+ will adversely affect reliability.
- 6. Shorting output to V- will adversely affect reliability.

Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
V ⁺ -V ⁻	Supply Voltage	2.7 to 5.5	V
T _A	Operating Ambient Temperature Range	-40 to +125	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

2.7V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_A = +25^{\circ}C$, $V^{\dagger} = 2.7V$, $V^{c} = 0V$, $V_{CM} = 1.0V$, $V_{O} = V^{\dagger}/2$ and $R_L > 1$ M Ω .

Symbol	Parameter	Test Conditions	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Unit
Vos	Input Offset Voltage			1.7	7	mV
TCVos	Input Offset Voltage Average Drift			5		μV/°C
I _B	Input Bias Current			10		nA
Ios	Input Offset Current			5	50	nA
CMRR	Common Mode Rejection Ratio	$0V \le V_{CM} \le 1.7V$	50	63		dB
PSRR	Power Supply Rejection Ratio	$2.7V \le V^{+} \le 5V, V_{O} = 1V$	50	60		dB
\/	Input Common-Mode Voltage Range	For CMRR ≥ 50dB	0	-0.2		V
V _{CMR}	Imput Common-wode Voltage Range	FOI CIVIRR 2 500B		1.9	1.7	V
V _O	Output Swing	$R_1 = 10 \text{ k}\Omega \text{ to } 1.35\text{V}$	V ⁺ - 100	V ⁺ - 20		mV
VO	Output Swing	KL = 10 KZ 10 1.33 V		20	100	IIIV
		LMV321 Single amplifier		110	140	μΑ
Is	Supply Current	LMV358 Both amplifiers		190	340	μΑ
		LMV324 All four amplifiers		340	680	μΑ
	2.7V AC Electrical Characteristics Unless otherwise specified, all limits guaranteed for $T_A = +25$ °C, $V^+ = 2.7V$, $V^- = 0V$, $V_{CM} = 1.0V$, $V_O = V^+/2$ and $R_L > 1$ M Ω .					
GBWP	Gain-Bandwidth Product	C _L = 200 pF		1		MHz
Фт	Phase Margin			60		Deg
Gm	Gain Margin			10		dB
e _n	Input-Referred Voltage Noise	f > 50 kHz		23		$\frac{nV}{\sqrt{H_z}}$

^{4.} Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

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Electrical Characteristics (cont.) (@TA = +25°C, unless otherwise specified.)

5V DC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for T_A = +25°C, V* = 5V, V* = 0V, V_{CM} = 2.0V, V_O = V*/2 and R_L > 1 MΩ.

Symbol	Parameter	Те	st Condition	s	Min (Note 8)	Typ (Note 7)	Max (Note 8)	Unit						
.,	Land Official Vallage	T _A = +25°C				1.7	7							
Vos	Input Offset Voltage	T _A = full range				9	mV							
TCV _{OS}	Input Offset Voltage Average Drift					5		μV/°C						
	1 15: 0	T _A = +25°C				15	250							
lΒ	Input Bias Current	T _A = full range					500	nA						
		T _A = +25°C				5	50							
I _{OS}	Input Offset Current	T _A = full range					150	nA						
CMRR	Common Mode Rejection Ratio	$0V \le V_{CM} \le 4.0V$			50	65		dB						
PSRR	Power Supply Rejection Ratio	$2.7V \le V^{+} \le 5V$ $V_{O} = 1V, V_{CM} = 1V$			50	60		dB						
\ /	Innut Common Made Voltage Dange				0	-0.2		W						
V _{CMR}	Input Common-Mode Voltage Range	For CMRR ≥ 50dB				4.2	4.0	V						
A_V	Large Signal Voltage Gain	$R_L = 2 k\Omega \text{ (Note 9)}$			15	100		V/mV						
AV	Large digital voltage dairi	N = 2 K12 (Note 9)	T _A = full ran	ge	10			V/111V						
	Output Swing	$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{V}$	High level	T _A = +25°C	V ⁺ - 300	V ⁺ -50		mV						
				T _A = full range	V ⁺ - 400									
			Low level	$T_A = +25^{\circ}C$		50	300							
Vo				T _A = full range			400							
VO	Output Swing	D = 10 kO to 2 5 V	High level	T _A = +25°C	V ⁺ - 100	V ⁺ -10								
			D. = 10 kO to 2 5V	D. = 10 kO to 2 5\/	D. = 10 kO to 2 5\/	D. = 10 kO to 2 5\/	$P_{\rm c} = 10 k\Omega to 2.5 V$	R _L = 10 kΩ to 2.5V	P ₁ = 10 kO to 2 5\/	i ligit level	T _A = full range	V ⁺ - 200		
		N_ = 10 K12 t0 2.5V	Low level	$T_A = +25^{\circ}C$		10	180							
			T _A = full range			280								
lo	Output Short Circuit Current	Sourcing, V _O = 0V			5	60		mA						
10	Output Short Gircuit Guirent	Sinking, V _O = 5V			10	90		ША						
		LMV321 Single amp	lifier			110	140							
		LMV358 Both amplif	iers	T _A = +25°C		190	340	μΑ						
Is	Supply Current	Livi Voco Both umpin		T _A = full range			600							
		LMV324 All four amp	nlifiers	T _A = +25°C		340	680							
			pillicio	T _A = full range			1100							
		SOT353 (Note 10)				330								
		SOT25 (Note 10)				250								
θ_{JA}	Thermal Resistance Junction-to-	TSSOP-14 (Note 10)			100		°C/W						
2, .	Ambient	MSOP-8 (Note 10)				203								
		SO-8 (Note 10)			150									
		SO-14 (Note 10)			83									

5V AC Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $T_A = 25^{\circ}C$, $V^{\dagger} = 5V$, V = 0V, $V_{CM} = 2.0V$, $V_C = V^{\dagger}/2$ and $R_L > 1$ $M\Omega$. Boldface limits apply at the temperature extremes.

SR	Slew Rate	(Note 11)	1	V/µs
GBWP	Gain-Bandwidth Product	C _L = 200pF	1	MHz
Φ_{m}	Phase Margin		60	Deg
G _m	Gain Margin		10	dB
e _n	Input-Referred Voltage Noise	f > 50 kHz	23	$\frac{\text{nV}}{\sqrt{\text{H}_{\text{z}}}}$

Notes:

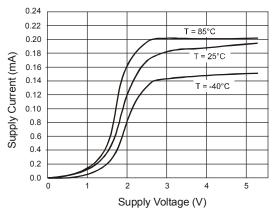
^{7.} Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

^{8.} All limits are guaranteed by testing or statistical analysis.

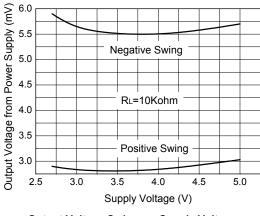
<sup>O. All initials are guaranteed by testing of statistical artistics.
O. R_L is connected to V-. The output voltage is 0.5V ≤ V_O ≤ 4.5V.
All numbers are typical, and apply for packages soldered directly onto a PC board in still air.
Connected as voltage follower with 3V step input. Number specified is the slower of the positive and negative slew rates.</sup>



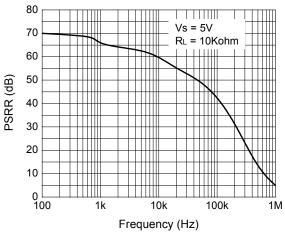
Typical Performance Characteristics (V_S = +5V, single supply, @T_A = +25°C, unless otherwise specified.)



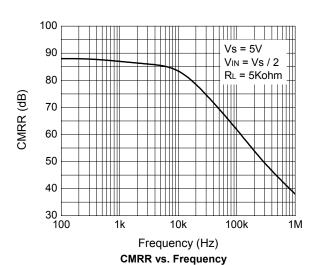
Supply Current vs. Supply Voltage

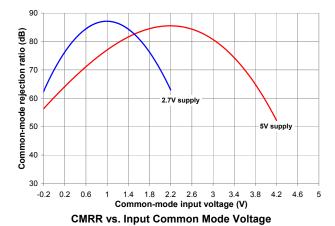


Output Voltage Swing vs. Supply Voltage



PSRR vs. Frequency





1.8

1.6

1.4 1.2

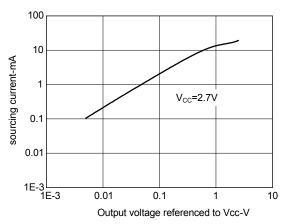
0.8

0.6 0.4 0.2

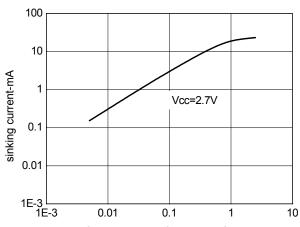
-0.2 0.2 0.6

Input offset voltage (mV)

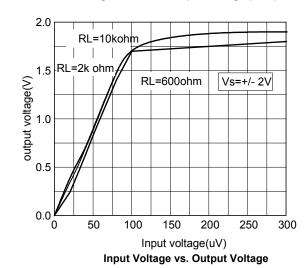


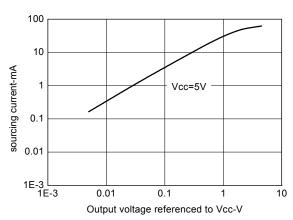


Sourcing Current vs. Output Voltage (2.7V)

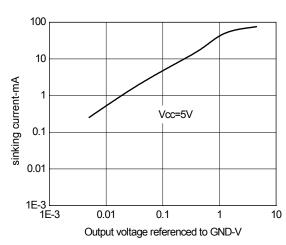


Output voltage referenced to GND-V Sinking Current vs. Output Voltage (2.7V)

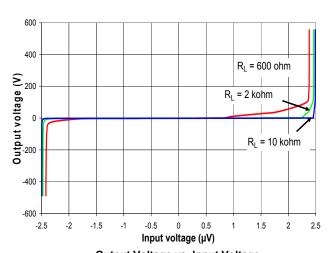




Sourcing Current vs. Output Voltage (5V)

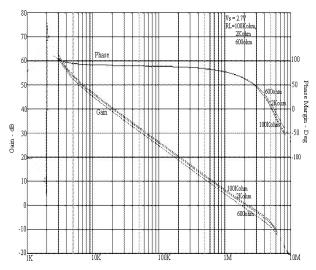


Sinking Current vs. Output Voltage (5V)

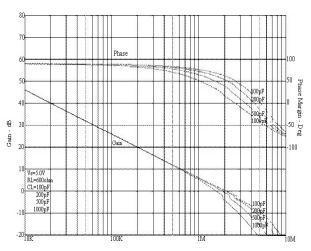


Output Voltage vs. Input Voltage

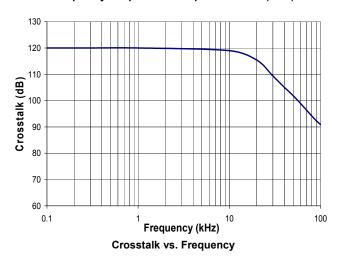


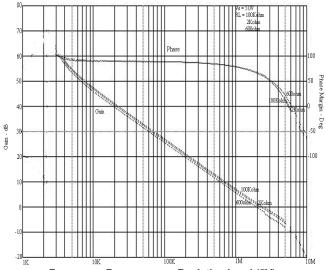


Frequency Response vs. Resistive Load (2.7V)

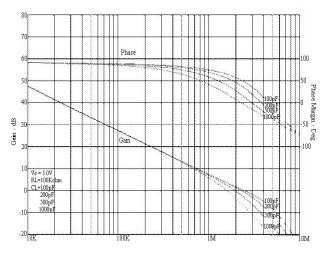


Frequency Response vs. Capacitive Load (2.7V)



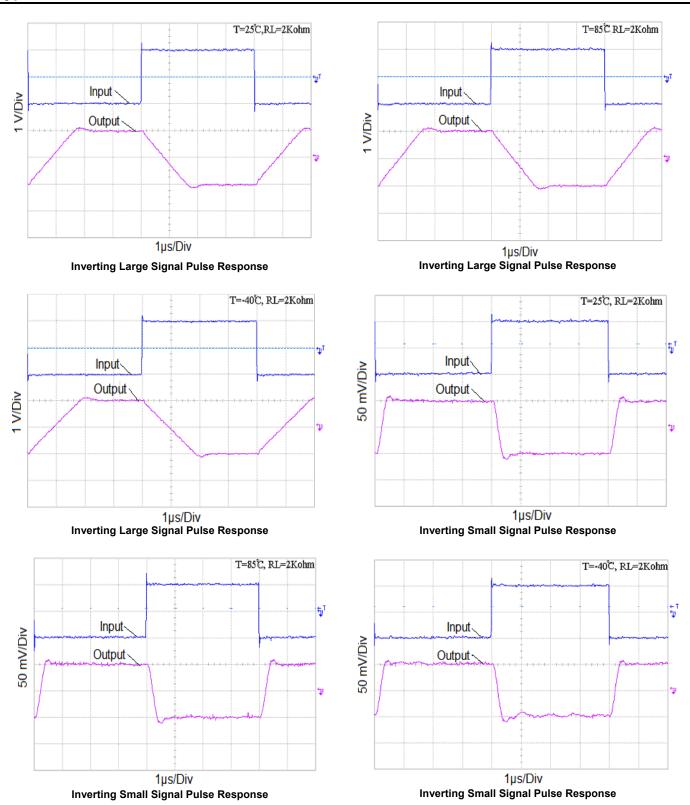


Frequency Response vs. Resistive Load (5V)

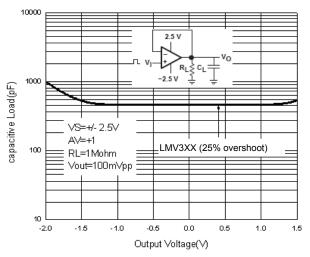


Frequency Response vs. Capacitive Load (5V)

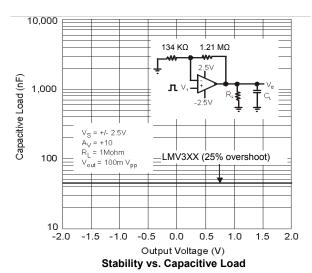








Stability vs. Capacitive Load



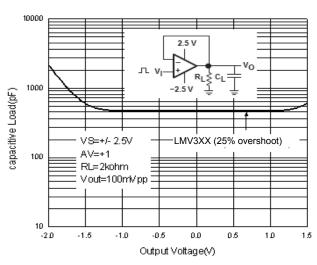
1.4 Rising Edge Av=+1
RL=10kohm
Vin=1Vpp

0.8

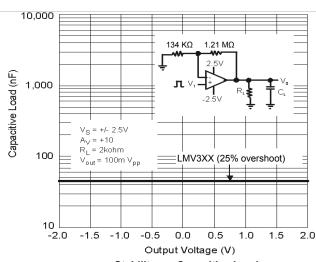
3.0
3.5
4.0
4.5
5.0

Supply Voltage (V)

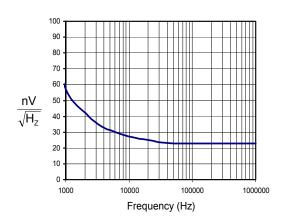
Slew Rate vs. Supply Voltage



Stability vs. Capacitive Load



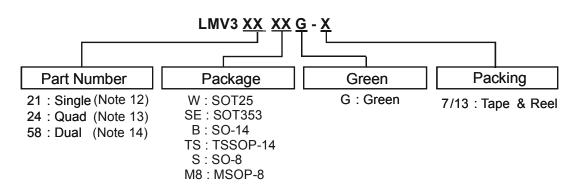
Stability vs. Capacitive Load



Input Voltage Noise



Ordering Information



	Part Number	Package Code	Packaging	7"/13" T	ape and Reel
	Part Number	Package Code	Packaging	Quantity	Part Number Suffix
Pb Green	LMV321WG-7	W	SOT25	3000/Tape & Reel	-7
Pb Green	LMV321SEG-7	SE	SOT353	3000/Tape & Reel	-7
Pby Lead free Green	LMV324BG-13	В	SO-14	2500/Tape & Reel	-13
Pb Green	LMV324TSG-13	TS	TSSOP-14	2500/Tape & Reel	-13
Pb Lead-free Green	LMV358SG-13	S	SO-8	2500/Tape & Reel	-13
Pb.	LMV358M8G-13	M8	MSOP-8	2500/Tape & Reel	-13

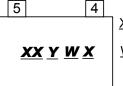
Notes:

- 12. LMV321 is only available for SOT25 and SOT353.
- 13. LMV324 is only available for SO-14 and TSSOP-14.
- 14. LMV358 is only available for SO-8 and MSOP-8.

Marking Information

SOT25/SOT353





XX: Identification Code

Y : Year : 0~9

<u>W</u>: Week: A~Z: 1~26 week; a~z: 27~52 week; z represents 52 and 53 week <u>X</u>: A~Z: Green

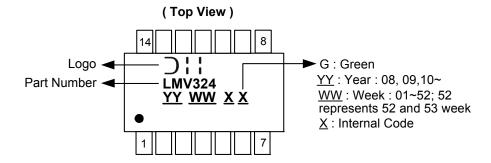
2 3

Device	Package type	Identification Code
LMV321W	SOT25	BX
LMV321SE	SOT353	BY

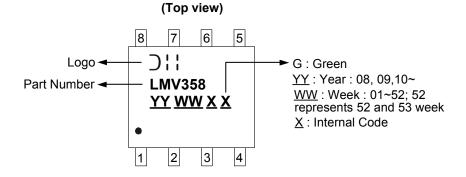


Marking Information (cont.)

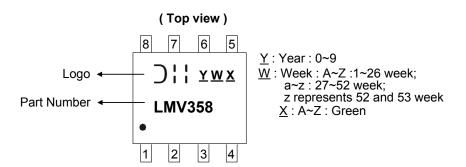
SO-14 / TSSOP-14



SO-8



MSOP-8

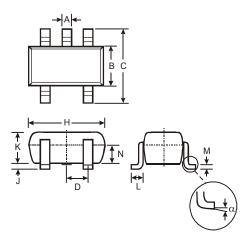




Package Outline Dimensions (All dimensions in mm.)

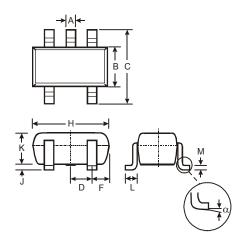
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

SOT25



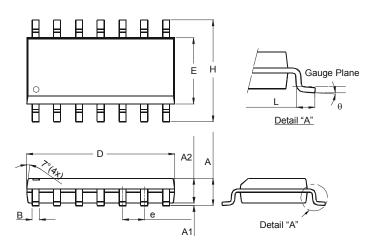
SOT25				
Dim	Min	Max	Тур	
Α	0.35	0.50	0.38	
В	1.50	1.70	1.60	
С	2.70	3.00	2.80	
D			0.95	
H	2.90	3.10	3.00	
7	0.013	0.10	0.05	
K	1.00	1.30	1.10	
L	0.35	0.55	0.40	
M	0.10	0.20	0.15	
N	0.70	0.80	0.75	
α	0°	8°		
All D	imensi	ons in	mm	

SOT353



SOT353					
Dim	Min	Max	Тур		
Α	0.10	0.30	0.25		
В	1.15	1.35	1.30		
С	2.00	2.20	2.10		
D	0	.65 Typ)		
F	0.40	0.45	0.425		
Н	1.80	2.20	2.15		
۲	0	0.10	0.05		
Κ	0.90	1.00	1.00		
٦	0.25	0.40	0.30		
М	0.10	0.22	0.11		
α	0°	8°	-		
All	Dimens	ions ir	n mm		

SO-14



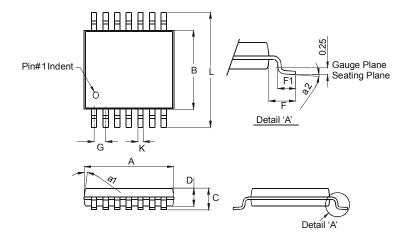
SO-14				
Dim	Min	Max		
Α	1.47	1.73		
A1	0.10	0.25		
A2	1.45	1.45 Typ		
В	0.33	0.51		
D	8.53	8.74		
Е	3.80	3.99		
е	1.27	Тур		
Н	5.80	6.20		
L	0.38	1.27		
θ	0°	8°		
All Di	mensions	s in mm		



Package Outline Dimensions (cont.) (All dimensions in mm.)

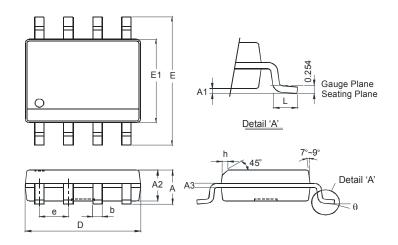
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

TSSOP-14



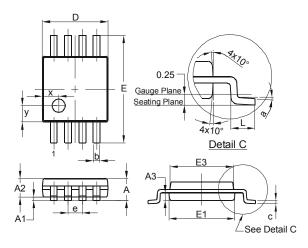
	TSSOP-1	4	
Dim	Min	Max	
a1	7° (4X)	
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
С	_	1.2	
D	8.0	1.05	
F	1.00	Тур	
F1	0.45	0.75	
G	0.65	Тур	
K	0.19	0.30	
L 6.40 Typ			
All Dir	nensions	s in mm	

SO-8



SO-8				
Dim	Min	Max		
Α	1	1.75		
A 1	0.10	0.20		
A2	1.30	1.50		
Α3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
E	5.90	6.10		
E1	3.85	3.95		
е	1.27	Тур		
h	1	0.35		
٦	0.62	0.82		
θ	0°	8°		
All Di	mensions	in mm		

MSOP-8



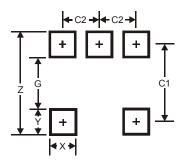
MSOP-8				
Dim	Min	Max	Тур	
Α	-	1.10	-	
A1	0.05	0.15	0.10	
A2	0.75	0.95	0.86	
A3	0.29	0.49	0.39	
b	0.22	0.38	0.30	
С	0.08	0.23	0.15	
D	2.90	3.10	3.00	
П	4.70	5.10	4.90	
E1	2.90	3.10	3.00	
E3	2.85	3.05	2.95	
е	ı	ı	0.65	
L	0.40	0.80	0.60	
а	0°	8°	4°	
X	-	-	0.750	
У	-	-	0.750	
All Dimensions in mm				



Suggested Pad Layout

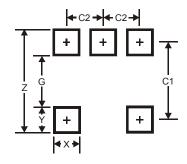
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

SOT25



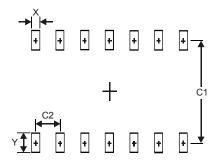
Dimensions	Value (in mm)	
Z	3.20	
G	1.60	
Х	0.55	
Y	0.80	
C1	2.40	
C2	0.95	

SOT353



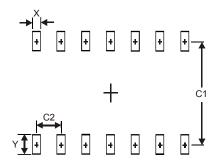
Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Υ	0.6
C1	1.9
C2	0.65

SO-14



Dimensions	Value (in mm)	
Х	0.60	
Y	1.50	
C1	5.4	
C2	1.27	

TSSOP-14



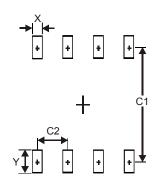
Dimensions	Value (in mm)
Х	0.45
Υ	1.45
C1	5.9
C2	0.65



Suggested Pad Layout (cont.)

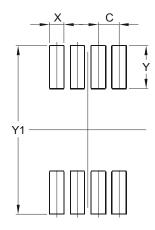
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

SO-8



Dimensions	Value (in mm)	
X	0.60	
Υ	1.55	
C1	5.4	
C2	1.27	

MSOP-8



Dimensions	Value (in mm)
C	0.650
Х	0.450
Y	1.350
V1	5 300



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